





High Efficiency Rectifier

Package: DO-27 Voltage: 50~1000 3 Ampers Volts **Current:** Diagram: **Features** NH'S High Efficiency Rectifier Chip Technology

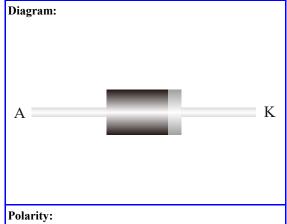
- - Low Switching Loss For High Efficiency
  - Low Leakage Current For High Reliability
  - Ultra Fast Switching Speed

#### **Mechanical Data**

- Case: Molded With UL-94 ClassV-0 Recognized, RoHS-Compliant
- Polarity: Look At The Diagram And Polarity On The Right
- Terminals: Tin Plated Leads, Solderable Per J-STD-002 And JESD22-B102

## **Typical Applications**

- Switch Mode Power Supplies (SMPS)
- Fast Chargers
- LED Driver And Monitor Lighting
- Automotive Electronics And Charging Posts





Single Phase, Half Wave, 60Hz, Resistive Or Inductive Load. For Capacitive Load, Derate Current By 20%

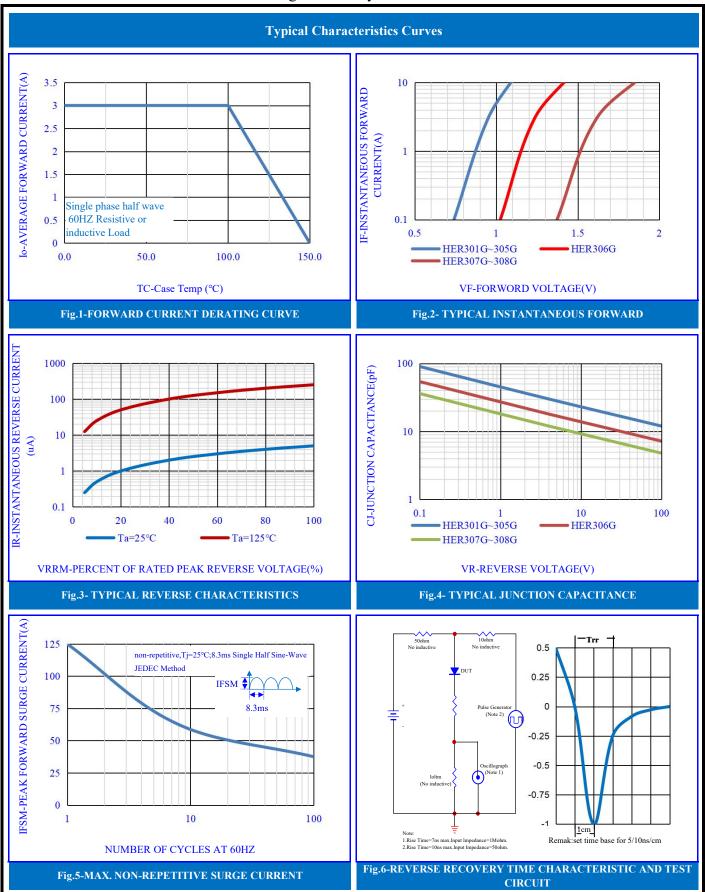
Maximum Ratings (Ta=25℃ Unless Otherwise Specified)										
Parameter Test Conditions		Symbol	HER 301G	HER 302G	HER 303G	HER 305G	HER 306G	HER 307G	HER 308G	Unit
Maximum Repetitive Peak Reverse Voltage		$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltag		$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		$I_{F(AV)}$				3				A
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	$I_{FSM}$				125				A
Current Squared Time	t< 8.3ms	I <sup>2</sup> t				64.8				A <sup>2</sup> sec

Electrical Characteristcs (Ta=25°C Unless Otherwise Specified )										
Parameter	Test Conditions	Symbol	HER 301G	HER 302G	HER 303G	HER 305G	HER 306G	HER 307G	HER 308G	Unit
Maximum Instaneous Forward Voltage	$I_F$ = 3.0 A	$\mathbf{V}_{\mathbf{F}}$		1.00		1.30	1.	70	V	
Maximum DC Reverse Current at Rated DC Blocking Voltage	$Ta=25$ °C , $V_R=VRRM$ $Ta=125$ °C , $V_R=VRRM*80$ %	$I_{RRM}$				5 200				uA uA
Typical Junction Capacitance	4 V,1MHz	$C_{J}$	30		18	1	2	pF		
Maximum Reverse Recovery Time	IF=0.5A, IR=1.0A, IRR=0.25A	Trr	Trr 50 75					nS		

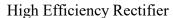
Thermal Characteristcs (Ta=25°C	Unless Otherwise Specified	)								
Parameter	Test Conditions	Symbol	HER 301G	HER 302G	HER 303G	HER 305G	HER 306G	HER 307G	HER 308G	Unit
Operating Junction Temperature Range		T <sub>J</sub> -55~150			ъ					
Storage Temperature Range		T <sub>STD</sub>	-55~150			C				
Thermal Resistance Junction To Ambient	Still Air Environment	$R_{\theta JA}$	65.0							
with Steady-State With 1a=25 C				°C/W						
Thermal Resistance Junction-Case With Steady-State	At 0.375"(9.5mm) lead length Mounted On vertical P.C. Board	$R_{\theta JC}$	20.0			0, ,,				
Netword Bullet Tests 200 He Bullet Wilds 10/ Dates Coult										

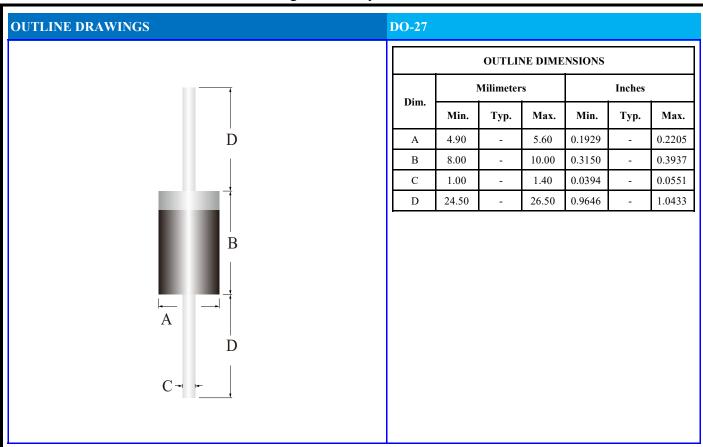


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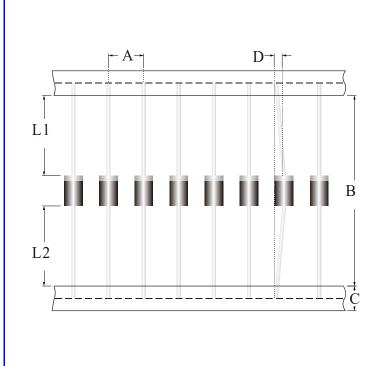








## COMPONENT PITCH DIMENSION DIAGRAM



### **DO-27**

OUTLINE DIMENSIONS								
ъ.	1	Milimeter	·s	Inches				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
A	9.50	ı	10.50	0.3740	ı	0.4134		
В	51.00	-	53.00	2.0079	-	2.0866		
С	5.50	1	6.50	0.2165	i	0.2559		
D	-		1.20	-	i	0.0472		
L2-L1	-		1.00	-	i	0.0394		





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MARKING	MARKING INSTRUCTION
HER3xxG	NH=Niuhang Trademark FF=Product Line Code,According To Actual Changes DDK=Inernal Code,According To Actual Changes HER3xxG=Model,x=01,02,03,05,06,07,08 White band denotes cathode

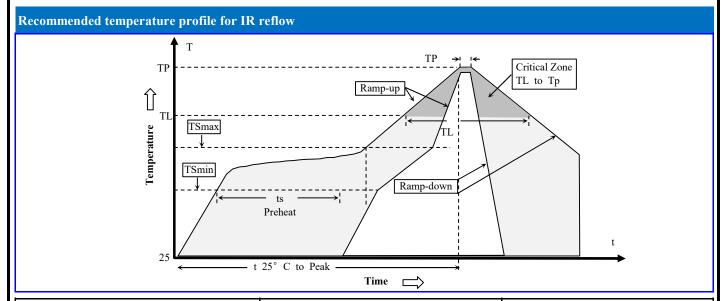
PACKING INFORMATION								
Package Type	Package Code	Productor Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)		
DO-27	P1	1	Tube	1000	1000	20000		
DO-27	P2	1	Tape	1250	1250	12500		





## High Efficiency Rectifier

Recommended wave soldering condition		
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat  -Temperature Min(TS min)  -Temperature Max(TS max)  -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above:  -Temperature (TL)  - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note: All temperatures refer to topside of the package, measured on the package body surface.

Http://www.nh-semicon.com Date:2014-10-20 Rev.:A/1 Page: 5 of 6

# Pb RoHS COMPLIANT

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